

DE2S05600L

Silicon epitaxial planar type

For ESD protection

■ Features

- High ESD
- Halogen-free / RoHS compliant
(EU RoHS / UL-94 V-0 / MSL:Level 1 compliant)

■ Marking Symbol: DC

■ Packaging

Embossed type (Thermo-compression sealing) 3 000 pcs / reel (standard)

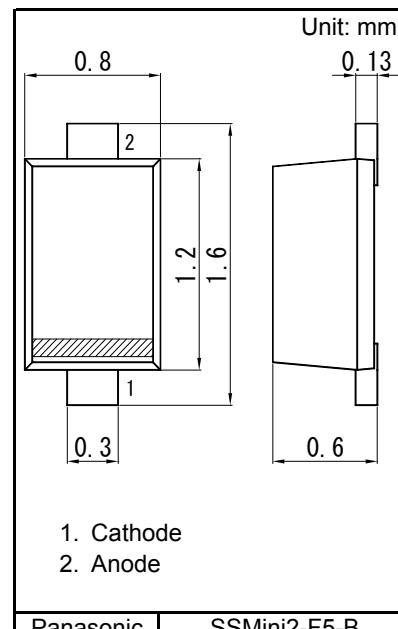
■ Absolute Maximum Ratings Ta = 25 °C

Parameter	Symbol	Rating	Unit
Total power dissipation ^{*1}	PT	150	mW
Electrostatic discharge ^{*2}	ESD	±30	kV
Junction temperature	T _j	150	°C
Operating ambient temperature	T _{opr}	-40 to +85	°C
Storage temperature	T _{stg}	-55 to +150	°C

Note) *1: Mounted on glass epoxy print board. (45 mm x 45 mm x 1 mm)

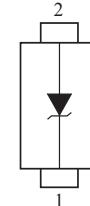
Solder in (0.8 mm x 0.6 mm)

*2: Test method:IEC61000_4_2(C = 150 pF, R = 330 Ω, Contact discharge:10 times)



Panasonic	SSMini2-F5-B
JEITA	SC-79
Code	SOD-523

Internal Connection



■ Electrical Characteristics Ta = 25 °C ± 3 °C

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Zener voltage ^{*1,*2}	VZ	I _Z = 1 mA	5.32		5.88	V
Reverse current	I _R	V _R = 2.5 V			0.5	μA
Terminal capacitance	C _t	V _R = 0 V, f = 1 MHz		65		pF
Temperature coefficient of zener voltage ^{*3}	S _Z	I _Z = 1 mA			1.8	mV/°C

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 Measuring methods for Diodes.

2. *1: The temperature must be controlled 25°C for VZ measurement.

VZ value measured at other temperature must be adjusted to VZ (25°C)

*2: VZ guaranteed 20 ms after current flow.

*3: T_j = 25°C to 150°C